

# THYRISTOR(Through Hole)

# SMG05C60

(Sensitive Gate)

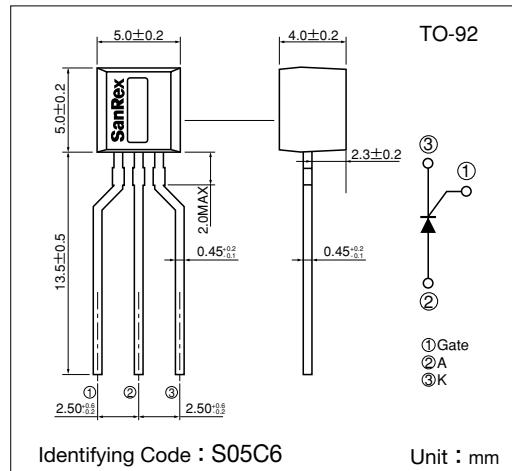
**SanRex** Thyristor **SMG05C60** is designed for full wave AC control applications. It can be used as an ON/OFF function or for phase control operation.

### Typical Applications

- Home Appliances : Electric Blankets, Starter for FL, other control applications
- Industrial Use : SMPS, Solenoid for Breakers, Motor Controls, Heater Controls, other control applications

### Features

- $I_{T(AV)}=0.5A$
- High Surge Current
- Low Voltage Drop



Identifying Code : S05C6

Unit : mm

### ■ Maximum Ratings

( $T_j=25^\circ\text{C}$  unless otherwise specified)

Symbol	Item	Reference	Ratings	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage		600	V
$V_{RSM}$	Non-Repetitive Peak Reverse Voltage		720	V
$V_{DRM}$	Repetitive Peak Off-State Voltage		600	V
$I_{T(AV)}$	Average On-State Current	Single phase, half wave, $180^\circ$ , conduction, $T_a=39^\circ\text{C}$	0.5	A
$I_{T(RMS)}$	R.M.S. On-State Current	Single phase, half wave, $180^\circ$ , conduction, $T_a=39^\circ\text{C}$	0.78	A
$I_{TSM}$	Surge On-State Current	50/60Hz, $\frac{1}{2}$ cycle Peak value, non-repetitive	18/20	A
$I^2t$	$I^2t$		1.65	$\text{A}^2\text{s}$
$P_{GM}$	Peak Gate Power Dissipation		0.5	W
$P_{G(AV)}$	Average Gate Power Dissipation		0.1	W
$I_{FGM}$	Peak Gate Current		0.3	A
$V_{FGM}$	Peak Gate Voltage (Forward)		6	V
$V_{RGM}$	Peak Gate Voltage (Reverse)		6	V
$T_j$	Operating Junction Temperature		-40~+125	$^\circ\text{C}$
$T_{stg}$	Storage Temperature		-40~+150	$^\circ\text{C}$
	Mass		0.2	g

### ■ Electrical Characteristics

Symbol	Item	Reference	Ratings			Unit
			Min.	Typ.	Max.	
$I_{DRM}$	Repetitive Peak Off-State Current	$T_j=125^\circ\text{C}$ , $V_D=V_{DRM}$ , $R_{GK}=1\text{k}\Omega$			0.5	mA
$I_{IRR}$	Repetitive Peak Reverse Current	$T_j=125^\circ\text{C}$ , $V_R=V_{RRM}$ , $R_{GK}=1\text{k}\Omega$			0.5	mA
$V_{TM}$	Peak On-State Voltage	$I_T=1.5\text{A}$ , Inst. measurement			1.2	V
$I_{GT}$	Gate Trigger Current	$V_D=6\text{V}$ , $R_L=100\Omega$			100	$\mu\text{A}$
$V_{GT}$	Gate Trigger Voltage				0.8	V
$V_{GD}$	Non-Trigger Gate Voltage	$T_j=125^\circ\text{C}$ , $V_D=\frac{1}{2}V_{DRM}$ , $R_{GK}=1\text{k}\Omega$	0.2			V
$I_H$	Holding Current			300		$\mu\text{A}$
$R_{th(j-a)}$	Thermal Resistance	Junction to ambient			150	$^\circ\text{C}/\text{W}$

